

## Supporting Information

### Vertically Aligned MoS<sub>2</sub> on Ti<sub>3</sub>C<sub>2</sub> (MXene) as an Improved HER Catalyst

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## Experimental Section

### Chemicals

All chemicals were analytical grade or technical grade and were used as received from the supplier (Fischer, Alfa Aesar and Sigma Aldrich) without further purification.

### Synthesis of $\text{Ti}_3\text{C}_2$

Synthesis of the  $\text{Ti}_3\text{AlC}_2$  MAX phase has been described previously.<sup>1</sup>  $\text{Ti}_3\text{C}_2$  MXene powder was prepared by the following etching procedure. One gram of  $\text{Ti}_3\text{AlC}_2$  powder was slowly added into a solution composed of 1 g lithium fluoride (LiF, Alfa Aesar, 98+ %) in 20 ml 9 M hydrochloric acid (HCl, Fisher, technical grade, 35-38%). This addition was followed by stirring at 35 °C for 24 h. The acidic suspension was washed with 100 ml of deionized (DI) water and centrifuged until a pH  $\geq 6$  was reached and a stable dark green supernatant of  $\text{Ti}_3\text{C}_2$  was collected after 30 min centrifugation at 3500 rpm. The resulting  $\text{Ti}_3\text{C}_2$  supernatant solution was filtered using a vacuum-assisted filtration through a polypropylene filter (3501 Coated PP, Celgard LLC, Charlotte, NC), followed by drying at room temperature under vacuum.

### Synthesis of the IE-MoS<sub>2</sub> and IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub> at different growth temperatures

The synthesis of the IE-MoS<sub>2</sub> was similar to the procedure developed by Sun Y. et al..<sup>2</sup> In brief 10 mg of (NH<sub>4</sub>)<sub>2</sub>MoS<sub>4</sub> (Alfa Aesar, 99.95%) was dispersed in 6 mL of DMF (Sigma Aldrich,  $\geq 99.8\%$ ). The mixture was stirred with the assistance of a magnetic stirrer at ambient conditions for 30 min to uniformly disperse the (NH<sub>4</sub>)<sub>2</sub>MoS<sub>4</sub>. The solution was then heated in a sealed vessel in a microwave (Monowave 300, Anton Parr) at the desired temperature for 2 h. The reaction vessel was quickly cooled to room temperature with a pressurized air flow. The product obtained was collected by centrifugation at 10000 rpm for 5 min, then washed with DI water followed by washing three times with a acetone/ethanol (1:1) mixture. The sample was dried in an oven overnight at 60 °C. In the case of the MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub> synthesis, the Ti<sub>3</sub>C<sub>2</sub> (5 mg) was initially sonicated in the DMF for 1 h before adding (NH<sub>4</sub>)<sub>2</sub>MoS<sub>4</sub> (10 mg). The resulting mixture

was stirred with the assistance of magnetic stirring for a further 30 min. Thereafter the procedure was similar to the synthesis of IE-MoS<sub>2</sub>.

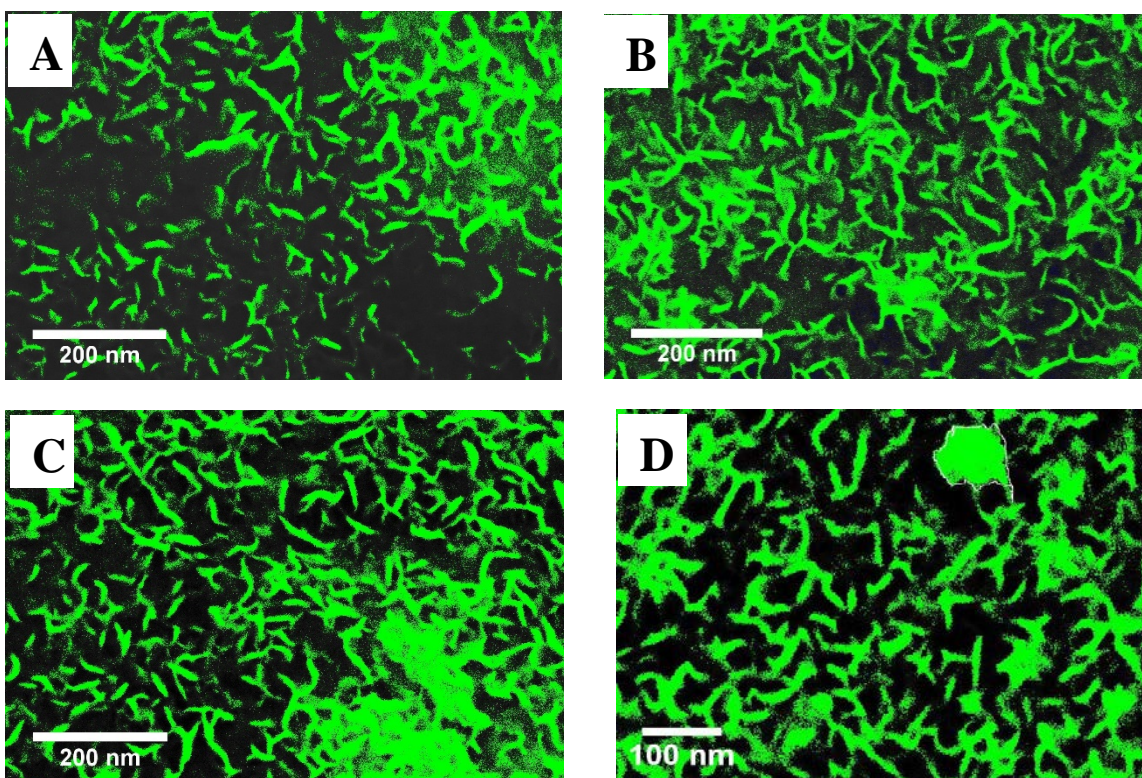
### **Characterization**

Samples for SEM were prepared by drop casting the sample of interest in a mixture of water/ethanol (4:1) on to a silicon wafer. SEM images were obtained with a FEG Quanta 450 FEG electron Microscope, operated at an acceleration voltage of 20 kV. Energy Dispersive X-ray Spectra (EDS) were obtained with an X-Max<sup>N</sup> 50 spectrometer (Oxford Instrument) mounted on the SEM. Samples for TEM were obtained by diluting the above samples with ethanol and drop casting them onto holey carbon grids. TEM and HRTEM images were recorded with a JEOL JEM-1400 microscope and JEOL JEM-2100 respectively. Raman measurements were performed using a Horiba Jobin Yvon Labram HR800 Evolution confocal Raman spectrometer with 532 nm laser excitation, Olympus MPlan N 100x microscope objective that focused excitation light to an ~1μm spot, and a 1800 gmm grating providing ~2 cm<sup>-1</sup> spectral resolution. Samples were drop cast onto a silicon wafer for Raman spectroscopy and dried in air overnight before collecting the spectra.

### **Electrochemical characterization**

Electrocatalytic were performed in an acidic media (0.5 M H<sub>2</sub>SO<sub>4</sub>) that was degassed by bubbling N<sub>2</sub> (for 20 min), using a CHI 660E potentiostat. The potentiostat operated in a standard three-electrode configuration at ambient temperature (20 ± 2 °C). All the potentials were measured with respect to a standard calomel reference electrode (CH instruments) and a Pt wire as the counter electrode. 5 μL of a catalyst ink suspension was drop cast on to a 3 mm diameter glassy carbon electrode (loading 50 μg) which was used as the working electrode. The electrode

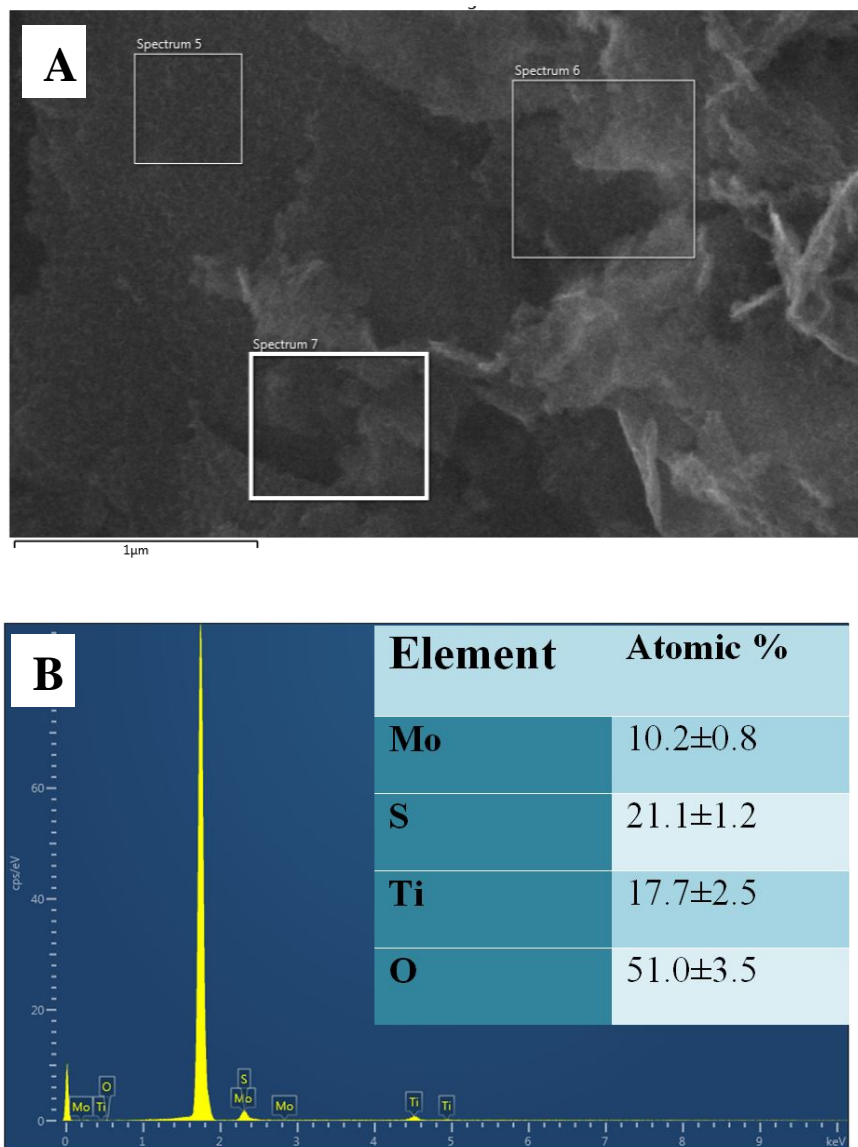
was dried in a fume hood for 30 min. The ink solution was prepared by adding 5 mg of the catalyst to 0.5 mL of an ethanol/DI water mixture (1:3), that was sonicated for 1 h. It should be noted that no binder (e.g. Nafion) was added when the catalyst ink was prepared. All the polarization curves were recorded at 10 mV/s scan rate after correcting for any iR losses. iR losses in the solution was determined to be (8-10  $\Omega$ ) by a CHI 660E potentiostat via the resistance test, which were then corrected from the polarization curves by subtracting iR (current x resistance) from the potential (V) . Polarization curves obtained with graphite rod counter electrode are given in SI figure 9. For all the catalysts tested here, polarization curves were replicated 3 times and obtained after cycling for 30 cycles. The onset potential, overpotential and Tafel slopes reported in this work are based on an analysis of these data. Chronopotentiometry measurements of each sample were carried out at a current density of 10 mA/cm<sup>2</sup><sub>geo</sub> for 20 h in 0.5 M H<sub>2</sub>SO<sub>4</sub> without any corrections for iR losses. Electrochemical Impedance Spectroscopy (EIS) Nyquist plots were obtained at 170 mV overpotential within the frequency range 0.1 Hz to 10<sup>6</sup> Hz. Cyclic voltamograms obtained at various scan rates (20, 40, 60, 80, 100, 120, 140 mVs<sup>-1</sup>) in the potential range 180-280 mV vs SCE were used to determine the ECSA and double layer capacitance. Electrochemical impedance spectroscopy was used to obtain Mott-Schottky plots. Experiments were carried out in 0.1 M Na<sub>2</sub>SO<sub>4</sub> solution (pH 7.2) at 100, 1000, and 10000 Hz.



**Figure S1:** Contrast profiles obtained from Imagej varying the threshold of the SEM images. These images were used to obtain the edge density given in table S1 for IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub> at growth temperatures of A) 200, B) 220, C) 240 and D) 260 °C. In the calculation of vertically aligned edges, the area from flower like morphologies (marked by the white line) have been subtracted from image D.

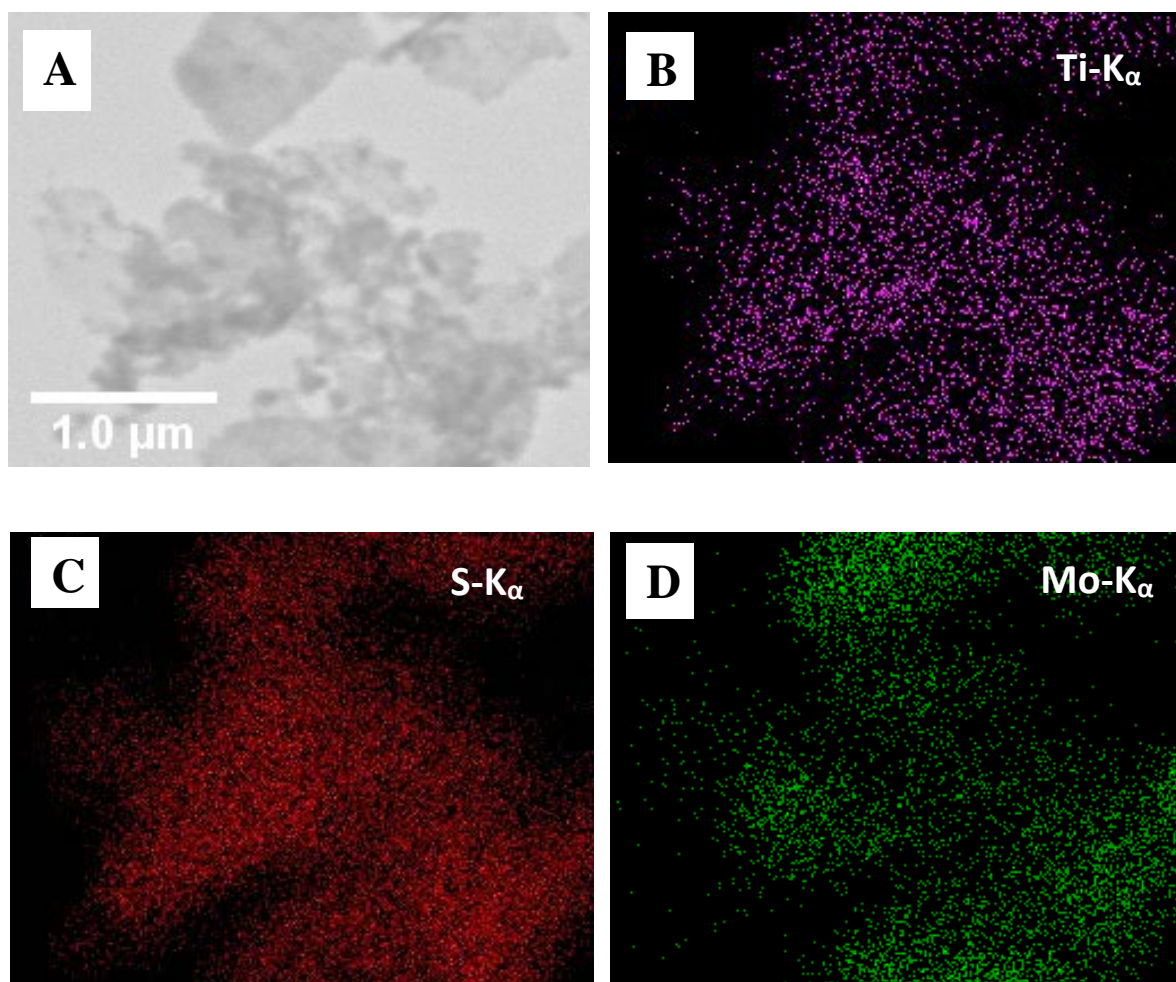
**Table S1:** Edge density of IE-MoS<sub>2</sub> grown on Ti<sub>3</sub>C<sub>2</sub>. The area with the green pixels were normalized to the total area of the image to obtain the density.

Image	Temperature (°C)	Edge density (%)
A	200	27.6
B	220	33.1
C	240	36.1
D	260	34.3



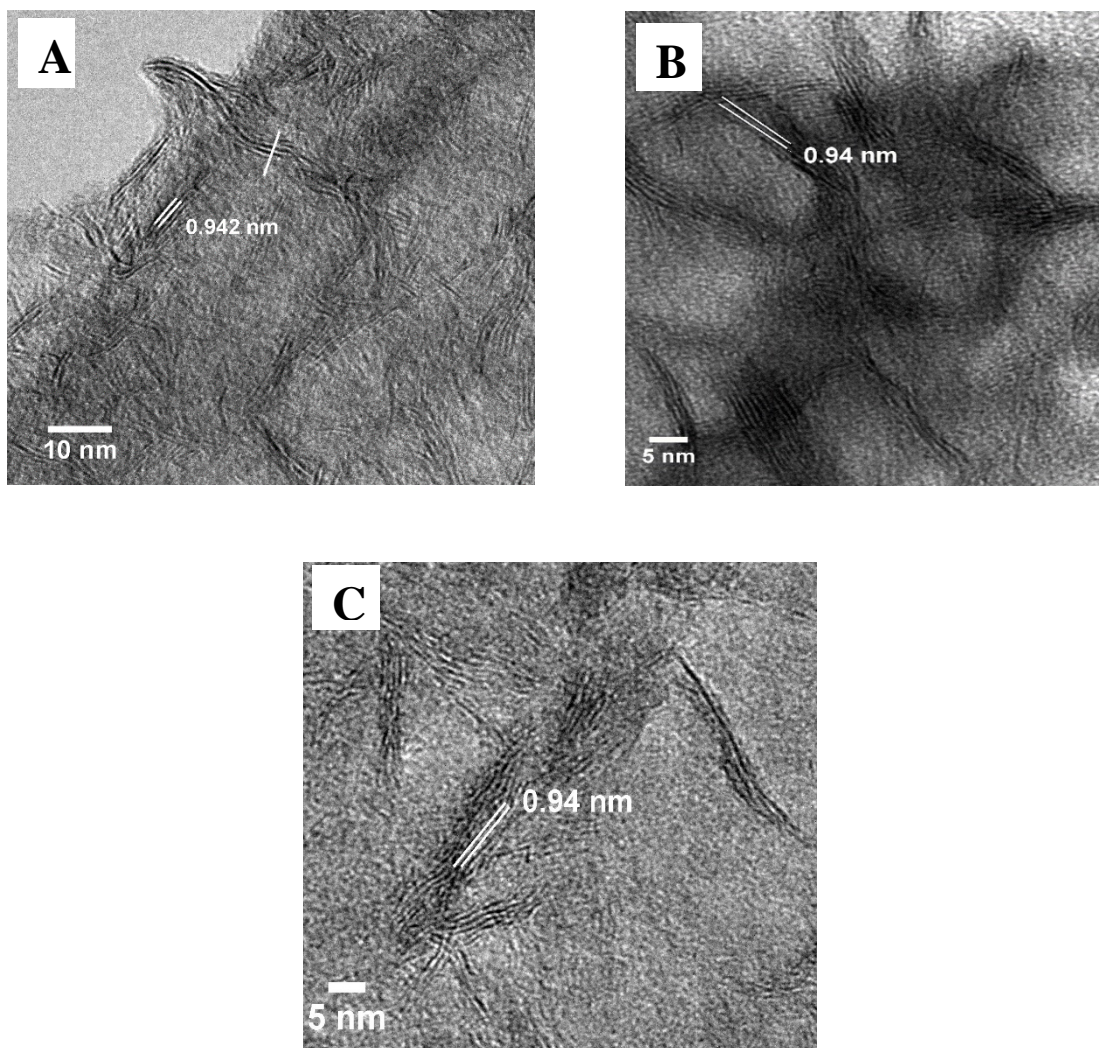
**Figure S2:** A) SEM micrograph of IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>@240 showing three regions used for quantifying the atomic percentages of Ti, Mo and S with EDS, B) Intensity maps of the EDS spectra for different Ti, Mo and S (inset: average atomic percentage of each component).



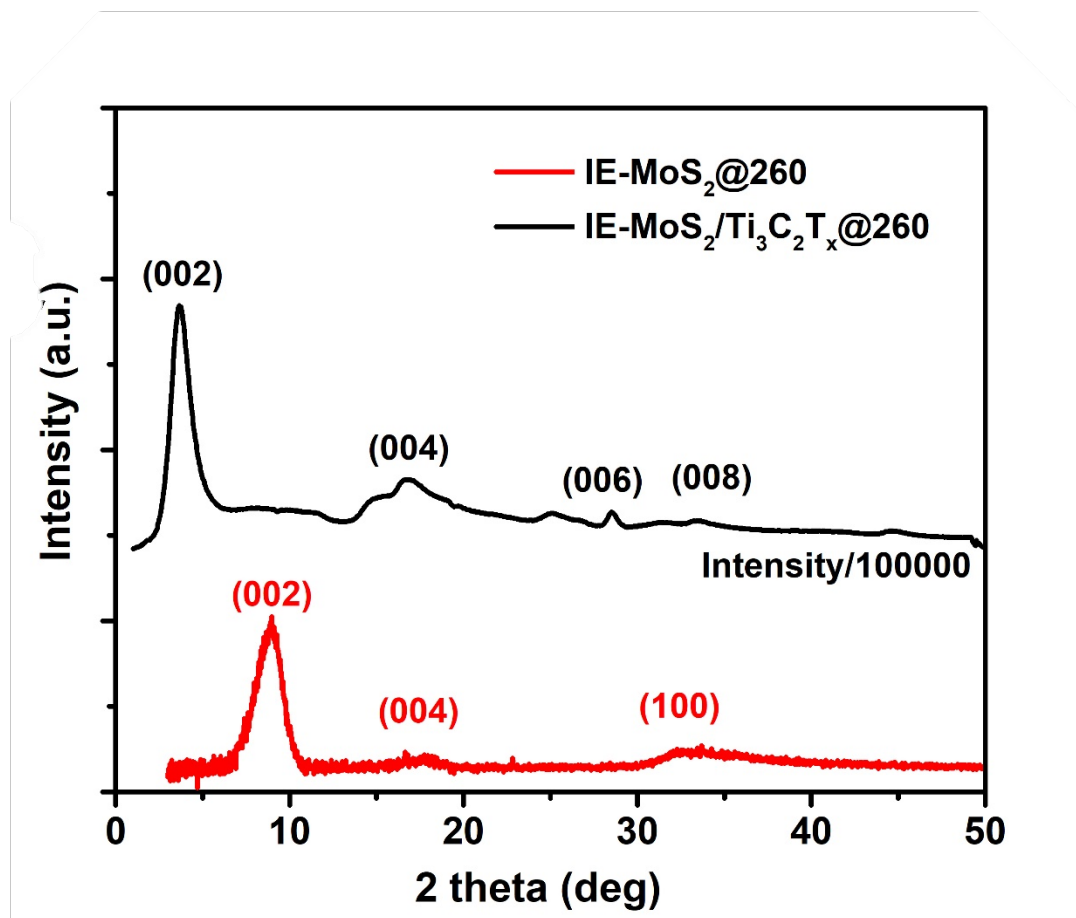


**Figure S3:** A) STEM image and B), C) and D)STEM-EDS maps of the elemental composition of the IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>@240.

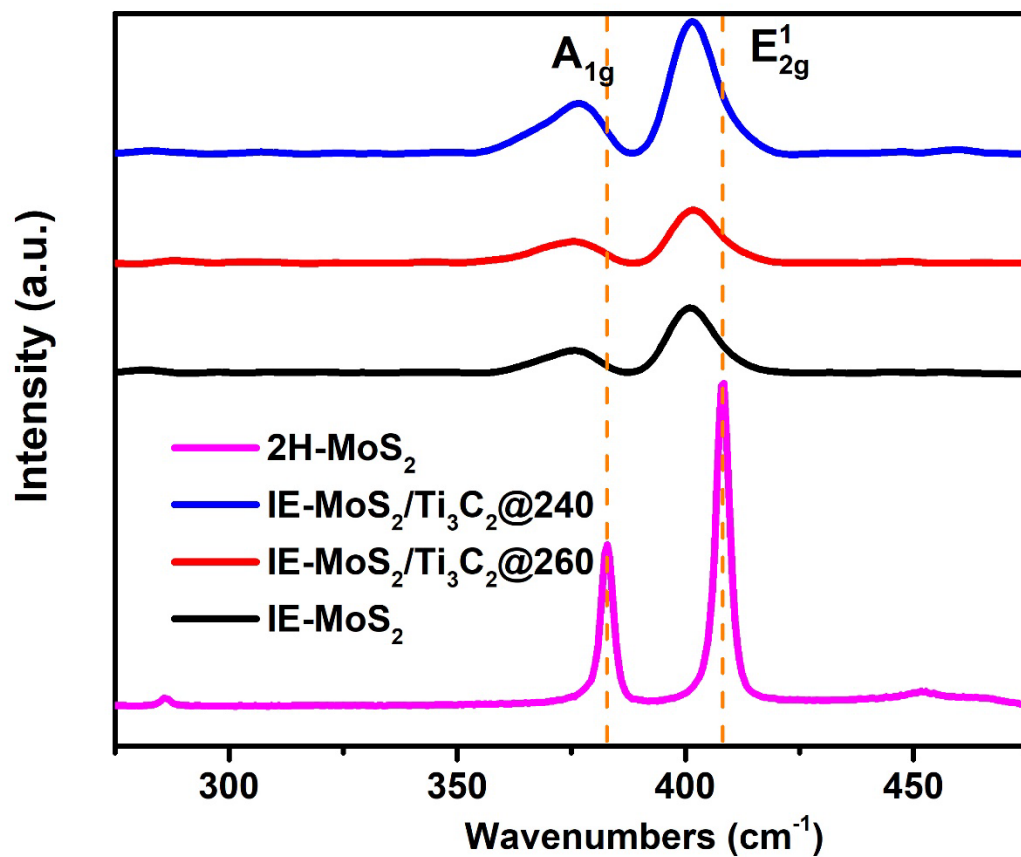




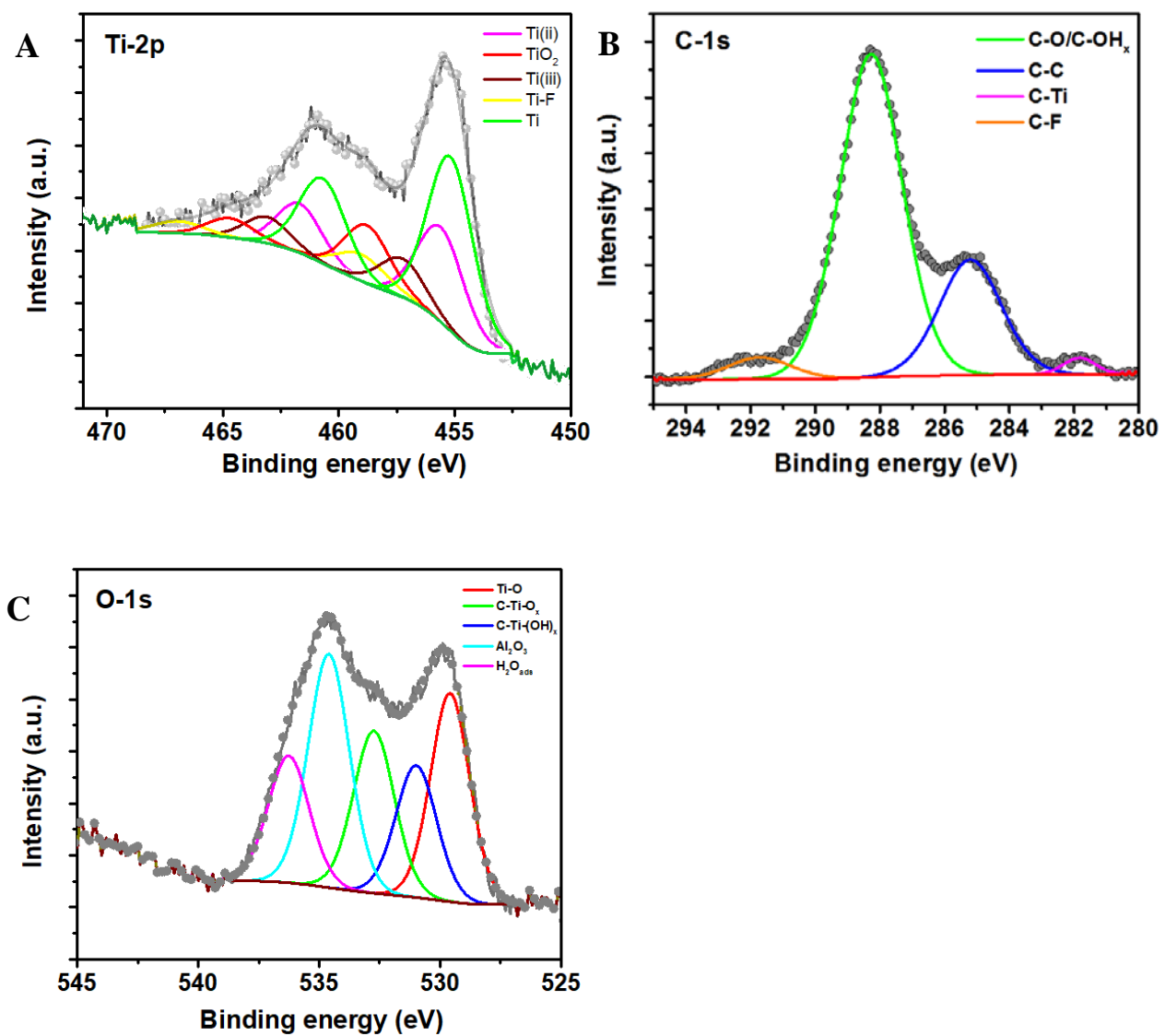
**Figure S4:** A), B) and C) HRTEM images of  $\text{MoS}_2/\text{Ti}_3\text{C}_2$  for samples grown at a) 200, b) 220 and c) 260  $^{\circ}\text{C}$ . These images show that the interlayer spacing of each is  $\sim 0.94$  nm irrespective of the temperature of synthesis.



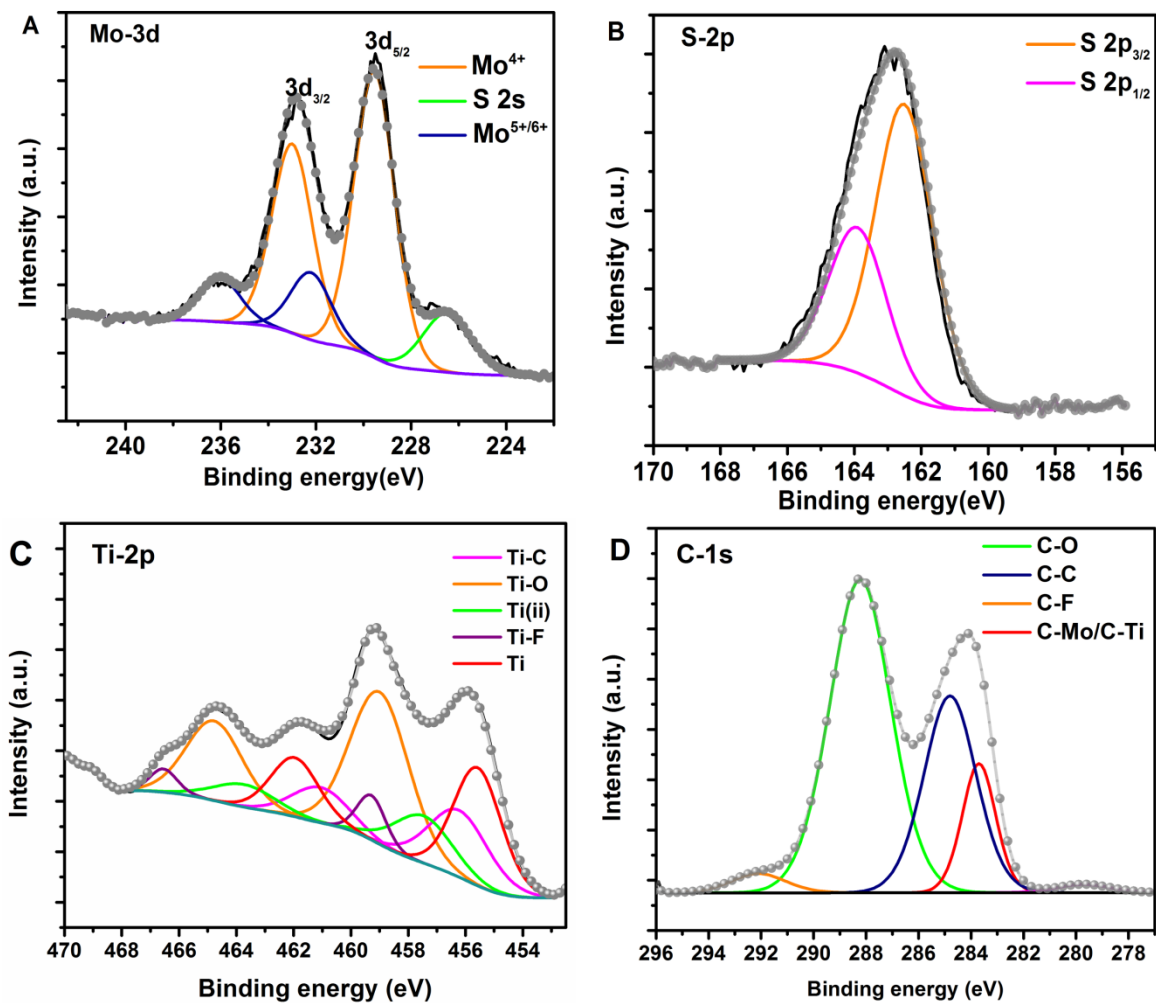
**Figure S5:** XRD diffractogram for IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>@260 (black) normalized by dividing by a factor of 100000. The relatively weak (002) at 9.4°, (004) at 18.8° and (100) at 32.2° Bragg reflection peak of MoS<sub>2</sub> (red) of interlayer expanded MoS<sub>2</sub> is not seen in this diffractogram of IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>@260 due to the masking of the peaks by the more intense peaks of the MXene.



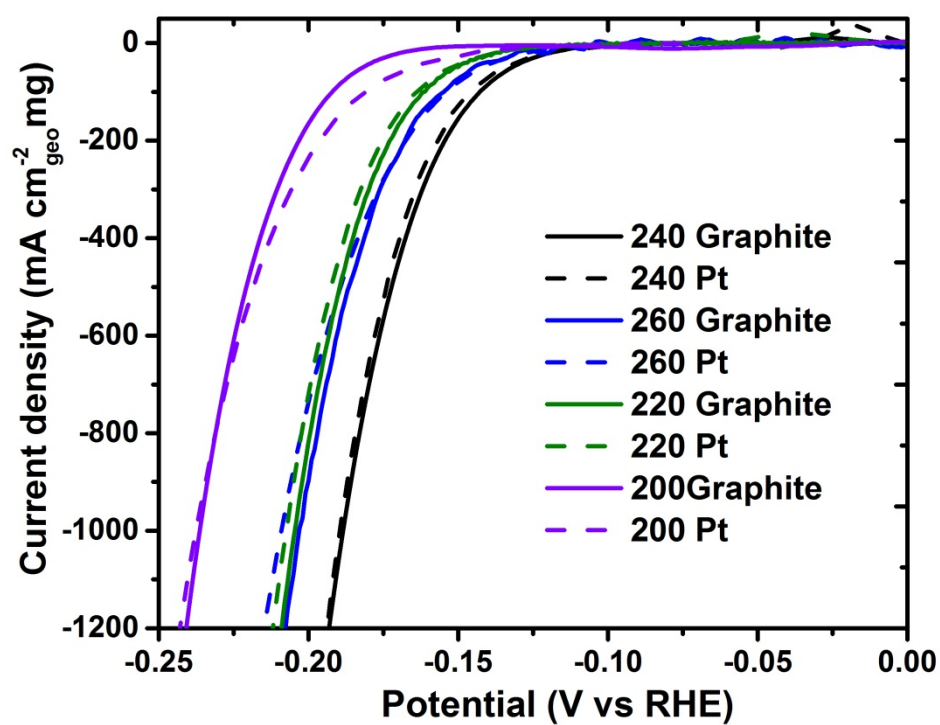
**Figure S6:** Comparison of the Raman spectra of IE-MoS<sub>2</sub> and the heterostructures synthesized at 240 and 260 °C. A blue shift is observed in the IE-MoS<sub>2</sub> and heterostructures relative to commercial 2H-MoS<sub>2</sub>.



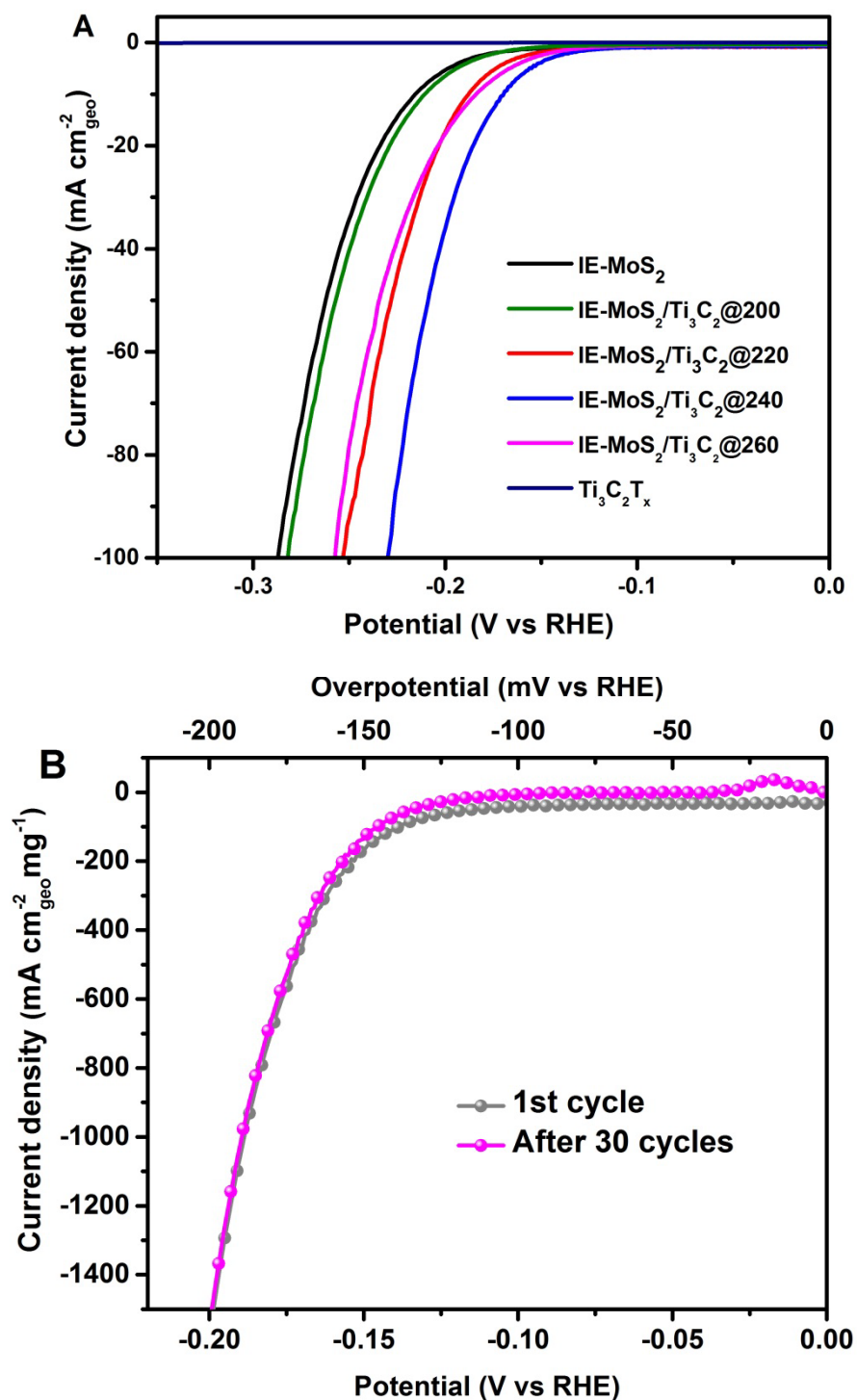
**Figure S7:** XPS spectra for the A) Ti 2p, B) C 1s, and C) O 1s region for Ti<sub>3</sub>C<sub>2</sub> before nucleating MoS<sub>2</sub>.



**Figure S8:** XPS for the A) Mo-3d, B) S-2p, C) Ti-2p and D) C-1s region for IE- $\text{MoS}_2/\text{Ti}_3\text{C}_2$  @ 240  $^{\circ}\text{C}$ .

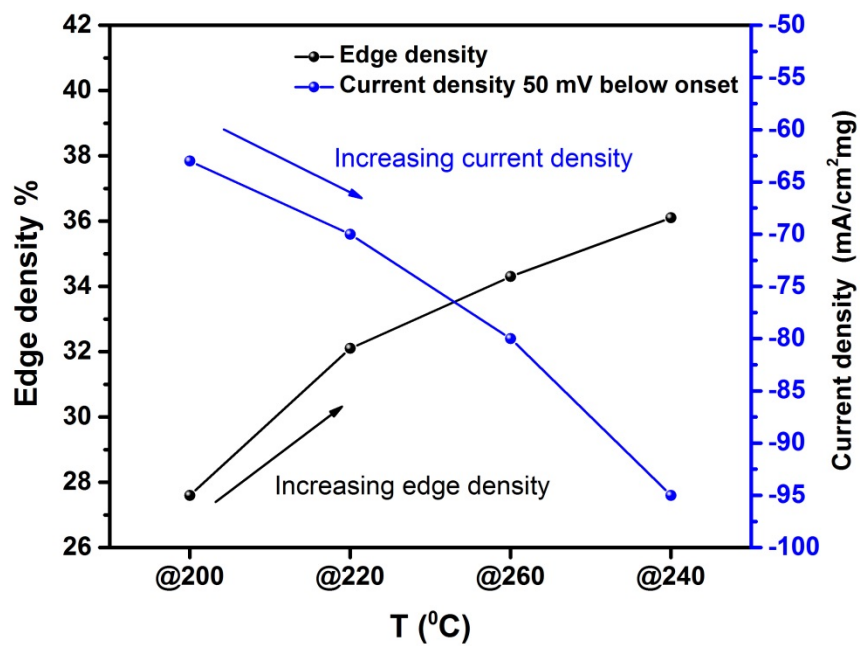


**Figure S9:** Polarization plots obtained after cycling for 1000 cycles in 0.5 M H<sub>2</sub>SO<sub>4</sub> with a Pt counter electrode and a graphite rod counter electrode. These LSV curves are almost identical to each other implying there had not been an influence of the counter electrode used.

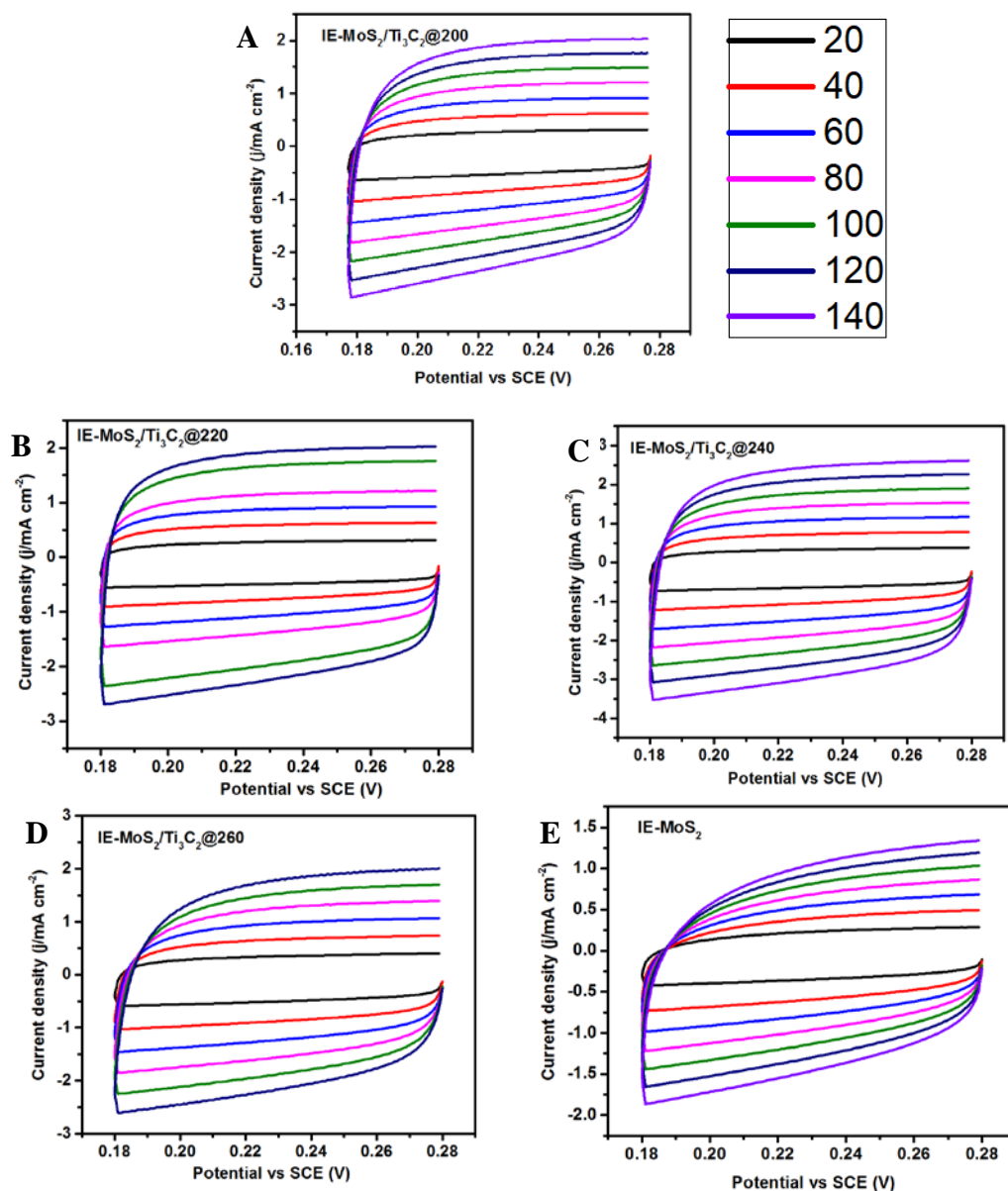


**Figure S10:** A) Polarization plot normalized to geometric surface area of the electrode. The MXene alone shows a high overpotential of  $\sim 500$  mV @  $10 \text{ mA/cm}^2$ . B) Polarization plot of IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>T<sub>x</sub>@240 °C for the first and 30<sup>th</sup> cycle. The cycling reduced capacitive background currents in the polarization curves.

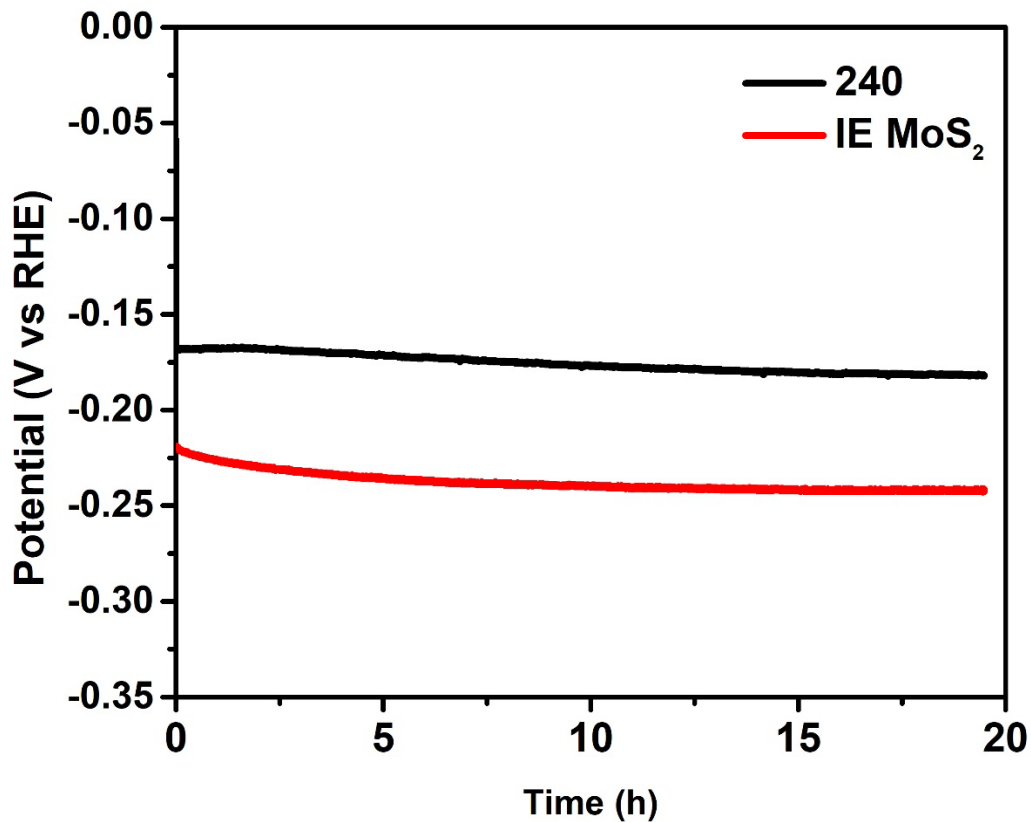




**Figure S11:** Comparison of current density (50 mV below the onset) and edge density of samples prepared at different temperatures. The current density increases with the increasing edge density of MoS<sub>2</sub> on the Ti<sub>3</sub>C<sub>2</sub> MXene.



**Figure S12 :** Cyclic voltammetry (CV) curves obtained in 0.5 M H<sub>2</sub>SO<sub>4</sub> from 180 to 280 mV vs SCE to investigate the capacitive currents used to calculate the electrochemically active surface area of the catalysts synthesized at different temperatures. The legend on the top right corner gives the scan rates (20, 40, 60, 80, 100, 120 and 140 mV/s). The presence of rectangular CVs implies the currents are non-faradaic and are capacitive.



**Figure S13:** Chronopotentiometry at  $10 \text{ mA/cm}^2_{\text{geo}}$  of the IE-MoS<sub>2</sub> and the heterostructure synthesized at  $240^\circ\text{C}$  over a period of 20 h in  $0.5 \text{ M H}_2\text{SO}_4$ . The catalysts show good stability in the region in the time period the tests were carried out with less than 7% decrease in potential to maintain a constant current of  $10 \text{ mA/cm}^2_{\text{geo}}$ .

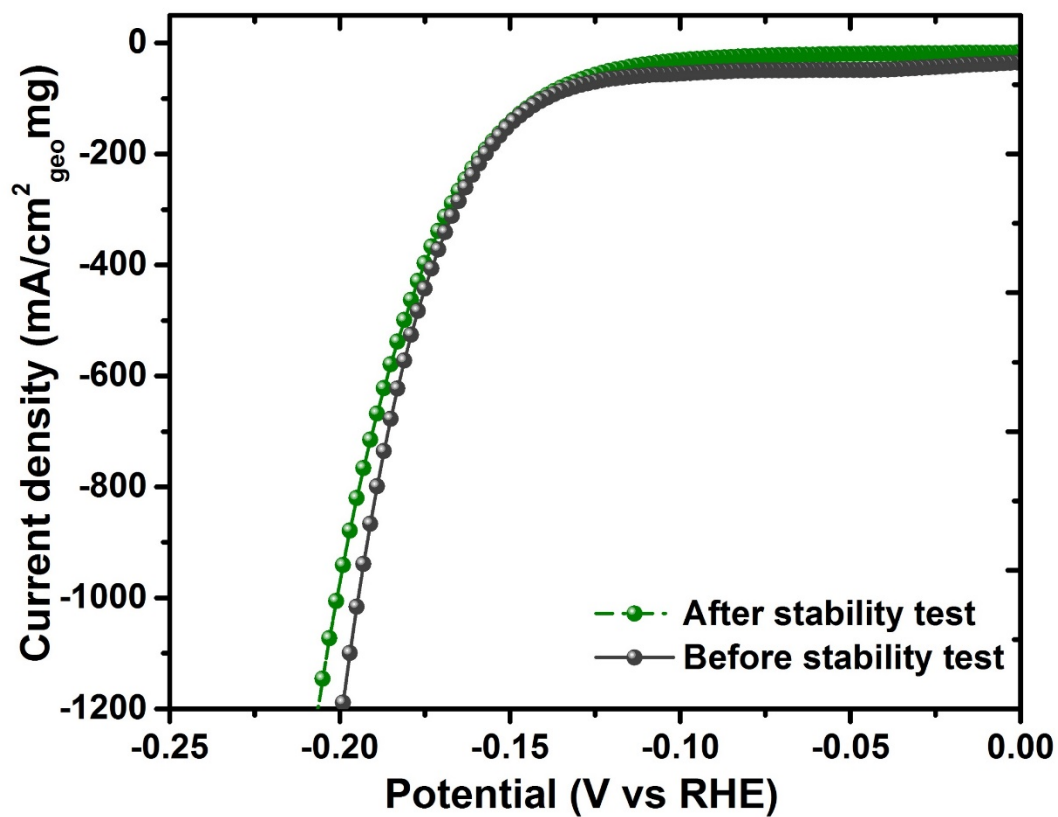


Figure S14: Polarization plots obtained before and after the stability (chronopotentiometry) test for IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>@240 °C.

The Mott-Schottky plots of IE-MoS<sub>2</sub>/Ti<sub>3</sub>C<sub>2</sub>@T where T is 200, 220, 240 and 260 °C were obtained in 0.1 M Na<sub>2</sub>SO<sub>4</sub> vs a Ag/ AgCl reference electrode (Figure 5a). From the Mott-Schottky relation:

$$\frac{1}{C_{SCL}^2} = \frac{2}{e \epsilon \epsilon_0 N_D} \left( E - E_{FB} - \frac{kT}{e} \right)$$

Where C<sub>SCL</sub>-capacitance of the space charge layer, e is the charge of an electron,  $\epsilon_0$  is permittivity of free space 8.85x10<sup>-12</sup> F m<sup>-1</sup>,  $\epsilon$  is dielectric constant of MoS<sub>2</sub>, E is applied potential, E<sub>FB</sub> is flatband potential, N<sub>D</sub> is donor density, k is Boltzmann constant, T is Kelvin temperature.<sup>3-5</sup>

**Table S2:** Carrier concentration of MoS<sub>2</sub> grown on Ti<sub>3</sub>C<sub>2</sub>

Samples	Carrier concentration (cm <sup>-3</sup> )
IE-MoS <sub>2</sub> /Ti <sub>3</sub> C <sub>2</sub> @200	1.1785 × 10 <sup>20</sup>
IE-MoS <sub>2</sub> /Ti <sub>3</sub> C <sub>2</sub> @220	2.2701 × 10 <sup>20</sup>
IE-MoS <sub>2</sub> /Ti <sub>3</sub> C <sub>2</sub> @240	2.5996 × 10 <sup>20</sup>
IE-MoS <sub>2</sub> /Ti <sub>3</sub> C <sub>2</sub> @260	6.3213 × 10 <sup>20</sup>

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